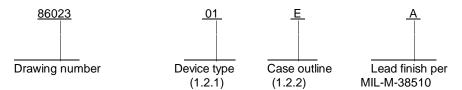
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Headquarters Ser Office of Manager PLEASE DO NOT ISSUING CONTR	vices, Direction nent and But RETURN \ ACTING OF	torate for Information Ope Idget, Paperwork Reduction YOUR COMPLETED FOR FFICER FOR THE CONTF	rations and Reports, on Project (0704-0188 :M TO EITHER OF TH RACT/ PROCURING	1215 Jefferson Davis Highv), Washington, DC 20503. HESE ADDRESSED. RETI ACTIVITY NUMBER LISTE	ne for reviewing instructions, s ormation. Send comments reg den, to Department of Defenss vay, Suite 1204, Arlington, VA URN COMPLETED FORM TO ED IN ITEM 2 OF THIS FORM	22202-4302, and to the OTHE GOVERNMENT .	3. DODAAC
b. ADDRESS (Street, City, State, Zip Code) 4. ORIGINATOR Defense Electronics Supply Center						5. CAGE CODE 67268	6. NOR NO. 5962-R156-96
a. TYPED NA <i>Last)</i>	TYPED NAME (First, Middle Initial, Last) 1507 Wilmington Pike Dayton, OH 45444-5765						8. DOCUMENT NO. 86023
9. TITLE OF [OCUME	NT	•		40 DEVIOLONI ETT		11. ECP NO.
MICROCIRO	CUIT, DIG	GITAL, BIPOLAR 256	6-BIT RAM, MON	NOLITHIC SILICON	10. REVISION LETT	I	N/A
					a. CURRENT A	b. NEW B	
12. CONFIGU	RATION	ITEM (OR SYSTEM	I) TO WHICH EC	P APPLIES			
13. DESCRIP	TION OF	REVISION					
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a. (X one)	Χ	(1) Existing docume	ent supplemented	d by the NOR may be	used in manufacture.		
		(2) Revised docum	ent must be rece	ived before manufactu	rer may incorporate this	s change.	
ľ		(3) Custodian of m	aster document s	shall make above revis	ion and furnish revised	document.	
b. ACTIVITY	AUTHOR	IZED TO APPROVE				rst, Middle Initial, Last)	
DESC-ELDS	S				Michael A. Frye	,	
d. TITLE				e. SIGNATURE			f. DATE SIGNED
Microelectro	nics Bran	ch Chief		Michael A. Frye			<i>(YYMMDD)</i> 96-06-26
15a. ACTIVIT	Y ACCON	MPLISHING REVISION	NC	b. REVISION COMP	PLETED (Signature)		c. DATE SIGNED
DESC-ELDS Kenneth			Kenneth S. Rice		(<i>YYMMDD</i>) 96-06-26		

REVISIONS																				
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1. SCOPE

- 1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883 "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".
 - 1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 <u>Device type</u>. The device type shall identify the circuit function as follows:

Device type Generic number Circuit 82S16 01 256-bit X 1 bipolar RAM

1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter Case outline

Ε D-2 (16 lead, 1/4" x 7/8"), dual-in-line package F F-5 (16 lead, 1/4" x 3/8"), flat package

1.3 Absolute maximum ratings.

Supply voltage+7 V dc maximum Output voltage+5.5 V dc maximum

Storage temperature range- 65° C to +150 $^{\circ}$ C Maximum power dissipation (P_D) 1/660 mW Lead temperature (soldering, 10 seconds)+300 $^{\circ}$ C

Thermal resistance, junction-to-case (θ_{JC}):

1.4 Recommended operating conditions.

Supply voltage+4.75 V dc to +5.25 V dc

Case operating temperature range (T_C) -55°C to +125°C Maximum high level input voltage+2.0 V dc

Maximum low level input voltage+0.8 V dc

 $\underline{1}$ / Must withstand the added P_D due to short circuit test (e.g., I_{OS}).

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2. APPLICABLE DOCUMENTS

2.1 <u>Government specification and standard</u>. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified ir MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Truth table. The truth table shall be as specified on figure 2.
 - 3.2.3 Logic diagram. The logic diagram shall be as specified on figure 3.
 - 3.2.4 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended case operating temperature range.
- 3.4 <u>Marking</u>. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part numbe listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shal state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

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		TABLE I. Electric	al performance cha	aracteristics.			
Test	Symbol	$\frac{1}{\text{Conditions}}$ -55° C ≤ T _C ≤ +125° C 4.75 V ≤ V _{CC} ≤ 5.25 V see figure 4		Group A subgroups	Limits	Max	Unit
High-level input voltage	V _{IH}	V _{CC} = maximum		1, 2, 3	2.0		V
Low-level input voltage	V _{IL}	V _{CC} = minimum		1, 2, 3		0.8	V
Clamp voltage	V _{IC}	V _{CC} = minimum, I _{IN} = -18 mA		1, 2, 3		-1.5	V
High-level output voltage	V _{OH} 2/	V _{CC} = minimum, I _{OH} =	1, 2, 3	2.4		V	
Low-level output voltage	V _{OL} <u>3</u> /	V _{CC} = minimum, I _{OL} = 16 mA		1, 2, 3		0.5	V
High-level input current	I _{IH} <u>4</u> /	V _{CC} = maximum, V _{IN} = 5.5 V		1, 2, 3		25	μА
Low-level input current	I _{IL} 4/	V _{CC} = maximum, V _{IN}	= 0.45 V	1, 2, 3		-250	μА
Hi-Z state output current	I _{OZ} _ <u>5</u> /	V _{CC} = maximum	V _{OUT} = 5.5 V	1, 2, 3		50	μА
			V _{OUT} = 0.45 V			-50	
Short circuit current	I _{OS}	V _{CC} = maximum,	V _O = 0 V	1, 2, 3	-15	-70	mA
V _{CC} supply current	I _{CC} 7/	$V_{CC} = \text{maximum, CE}_1$, or CE_2 , or $CE_3 = \text{high}$		1, 2, 3		120	mA
Address access time	T _{AA}	4.75 V ≤ V _{CC} ≤ 5.25 V See figure 5		9, 10, 11		70	ns
Chip enable access time	T _{CE}	4.75 V ≤ V _{CC} ≤ 5.25 V	1	9, 10, 11		40	ns

See footnotes at end of table.

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	TA	BLE I. Electrical performance characteristic	cs - Continued			
Test	Symbol	1/ Conditions	Group A	Limits		Unit
	,	-55° C ≤ T _C ≤ +125° C 4.75 V ≤ V _{CC} ≤ 5.25 V see figure 4	subgroups	Min	Max	
Disable time	T _{CD}	4.75 V ≤ V _{CC} ≤ 5.25 V	9, 10, 11		40	ns
Valid time	T _{WD}	4.75 V ≤ V _{CC} ≤ 5.25 V	9, 10, 11		55	ns
Address setup time	T _{WSA}	4.75 V ≤ V _{CC} ≤ 5.25 V	9, 10, 11	20		ns
Address hold time	T _{WHA}	4.75 V ≤ V _{CC} ≤ 5.25 V	9, 10, 11	10		ns
Data in setup time	T _{WSD}	4.75 V ≤ V _{CC} ≤ 5.25 V	9, 10, 11	50		ns
Data in hold time	T _{WHD}	4.75 V ≤ V _{CC} ≤ 5.25 V	9, 10, 11	10		ns
CE setup time	T _{WSC}	4.75 V ≤ V _{CC} ≤ 5.25 V	9, 10, 11	10		ns
CE hold time	T _{WHC}	4.75 V ≤ V _{CC} ≤ 5.25 V	9, 10, 11	10		ns
Write enable pulse width	T _{WP} <u>8</u> /	4.75 V ≤ V _{CC} ≤ 5.25 V	9, 10, 11	40		ns

- 1/ All voltage values with respect to ground.
- 2/ Measured with a logic high stored. Output sink current is supplied through a resistor to V_{CC}. 3/ Measured with a logic low stored and V_{IL} applied to CE₁, CE₂, and CE₃.

- 4/ Test each input one at a time.

 5/ Measured with V_{IH} applied to CE₁, CE₂, and CE₃.

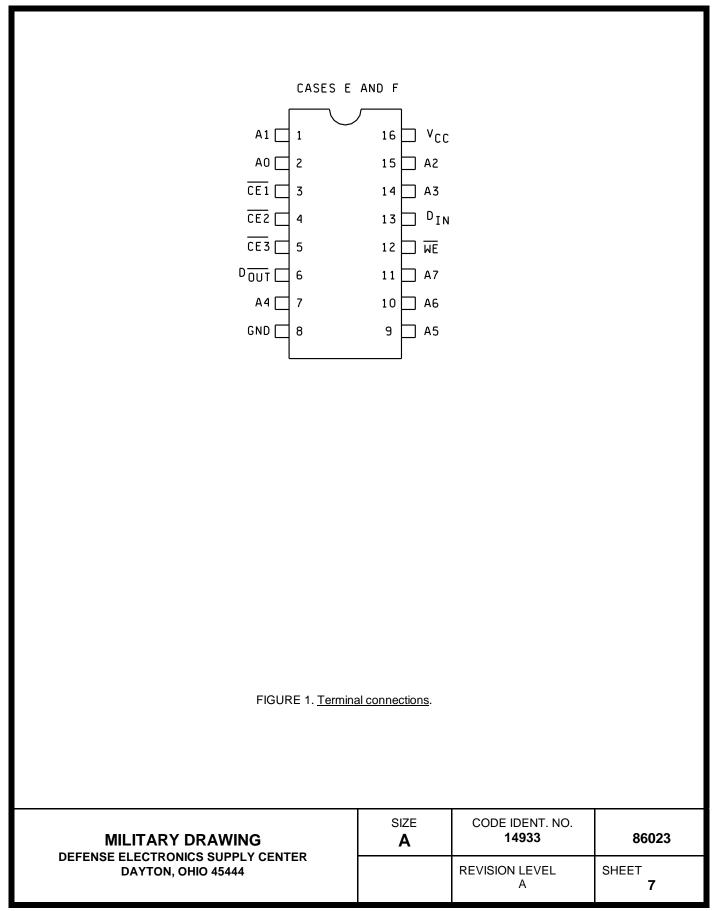
 6/ Duration of the short circuit should not exceed 1 second.

 7/ I_{CC} is measured with the write enable and memory enable inputs grounded, all other inputs at 4.5 V and the output open.
- 8/ Minimum required to guarantee a write into the slowest bit.

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- 3.6 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
 - 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test (method 1015 of MIL-STD-883).
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ} C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 4, 5, and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 4 (C_{IN} measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ} C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.

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MODE	Œ*	₩E	D _{IN}	D _{OUT}
Read	0	1	Х	<u>Stored</u> data
Write "0"	0	0	0	1
Write "1"	0	0	1	0
Disabled	1	Х	Х	Hi-Z

FIGURE 2. Truth table.

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^{* &}quot;0" = All \overline{CE} inputs low; "1" = One or more \overline{CE} inputs high. X = Don't care.

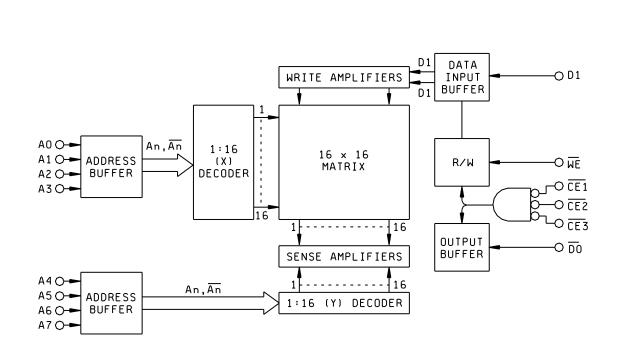
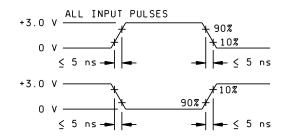


FIGURE 3. Logic diagram.

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INPUT PULSES



MEASUREMENTS ALL CIRCUIT DELAYS ARE MEASURED AT THE +15 LEVEL OF INPUTS AND OUTPUTS

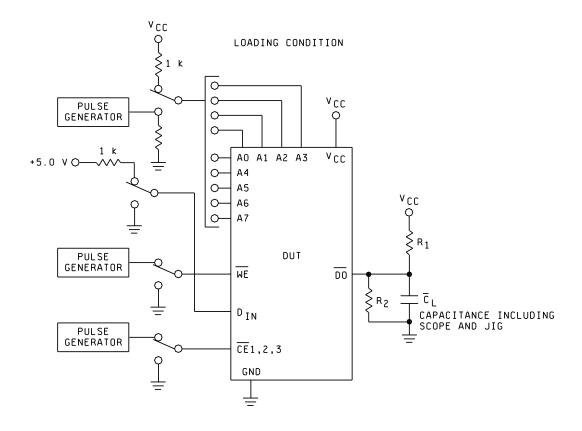
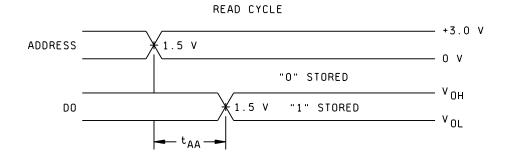


FIGURE 4. Test load circuit and voltage waveform.

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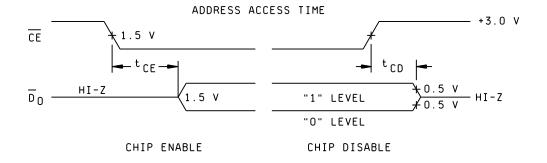
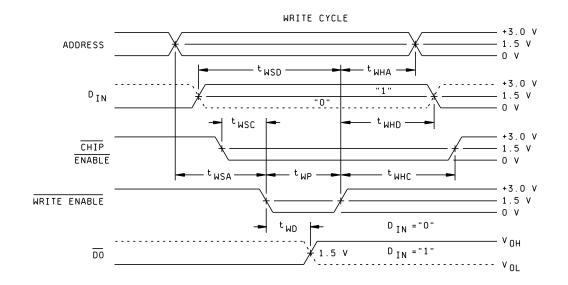


FIGURE 5. Timing diagrams.

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MEMORY TIMING DEFINITIONS

T_{CE} Delay between beginning of chip enable low (with address valid) and when data output becomes valid

T_{CD} Delay between when chip enable becomes high and data output is in off state.

T_{AA} Delay between beginning of valid address (with chip enable low) and when data output becomes valid.

T_{WSC} Required delay between beginning of valid chip enable and beginning of write enable pulse.

TWHD Required delay between end of write enable pulse and end of valid input data.

T_{WP} Write of write enable pulse.

TwsA Required delay between beginning of valid address and beginning of write enable pulse.

TWSD Required delay between beginning of valid data input and end of

write enable pulse.

TwD Delay between beginning of write

Delay between beginning of write enable pulse and when data output reflects complement of data input.

W_{WHC} Required delay between end of write enable pulse and end of chip enable.

TWHA Required delay between end of write enable pulse and end of valid address.

FIGURE 5. Timing diagrams - Continued.

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TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*,2,3,7,8,9
Group A test requirements (method 5005)	1,2,3,7,8, 9,10,11
Groups C and D end-point electrical parameters (method 5005)	1,2,3
Additional electrical subgroups for group C periodic inspections	

^{*} PDA applies to subgroup 1.

5. PACKAGING

5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Comments</u>. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

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6.4 <u>Approved source of supply</u>. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number <u>1</u> /	Replacement military specification part number
8602301EX	18324	82S16/BEA	
8602301FX	18324	82S16/BFA	

1/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE <u>number</u>

18324

Vendor name and address

Signetics, Incorporated 4130 S. Market Court Sacramento, CA 95834

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